NSN 5961-01-352-1798

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Internal Configuration:
Field effect
Semiconductor Material:
Gallium arsenide
Voltage Rating In Volts Per Characteristic:
-6.0 gate to source voltage
Current Rating Per Characteristic:
100.00 milliamperes drain current
Power Rating Per Characteristic:
400.0 milliwatts total power dissipation
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0